

## 1. Description

The DMG3414U-7(ES) is N-Channel enhancement MOS Field Effect Transistor. Uses advanced trench technology and design to provide excellent  $R_{DS(ON)}$  with low gate charge. Device is suitable for use in DC-DC conversion, power switch and charging circuit. Standard Product DMG3414U-7(ES) is Pb-free.

## 2. Features

- 20V,  $R_{DS(ON)}=25m\Omega$ (Typ.),  $V_{GS}=4.5V$
- $R_{DS(ON)}=29m\Omega$ (Typ.),  $V_{GS}=2.5V$
- High density cell design for low  $R_{DS(on)}$
- Material: Halogen free
- Reliable and rugged
- Avalanche Rated
- Low leakage current

## 3. Applications

- PWM applications
- Load switch
- Power management in portable/desktop PCs
- DC/DC conversion

## 4. Ordering Information

Part Number	Package	Marking	Material	Packing	Quantity per reel	Flammability Rating	Reel Size
DMG3414U-7(ES)	SOT-23	2300	Halogen free	Tape & Reel	3,000 PCS	UL 94V-0	7 inches

Table-1 Ordering information

## 5. Pin Configuration and Functions

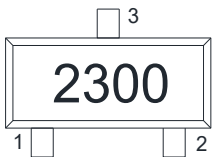
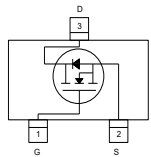
Pin	Function	Outline	Circuit Diagram
1	Gate		
2	Source		
3	Drain		

Table-2 Pin configuration

## 6. Specification

### Absolute Maximum Rating & Thermal Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified.

Parameter		Symbol	Limit	Unit
Drain-Source Voltage		$BV_{DSS}$	20	V
Gate-Source Voltage		$V_{GS}$	±12	V
Continuous Drain Current	$T_A=25^{\circ}C$	$I_D$	4	A
	$T_A=100^{\circ}C$		3	
Maximum Power Dissipation		$P_D$	1.2	W
Pulsed Drain Current		$I_{DM}$	16	A
Operating Junction Temperature		$T_J$	150	°C
Lead Temperature		$T_L$	260	°C
Storage Temperature Range		$T_{stg}$	-55 to 150	°C

### Thermal resistance ratings

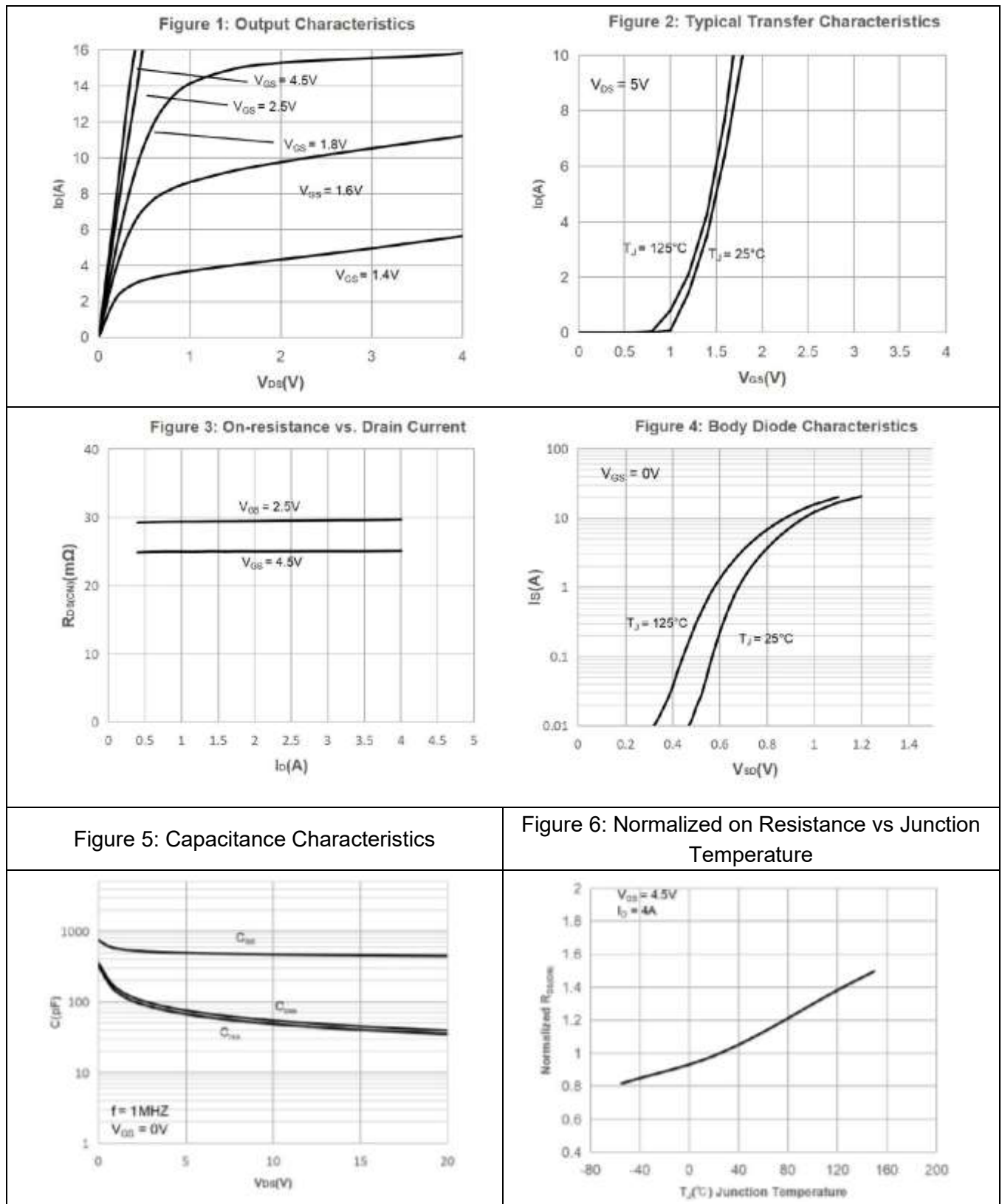
Single Operation				
Parameter	Symbol	Typical	Maximum	Unit
Junction-to-Ambient Thermal Resistance	$R_{\theta JA}$		106	°C/W

## Electrical Characteristics

At TA = 25°C unless otherwise specified

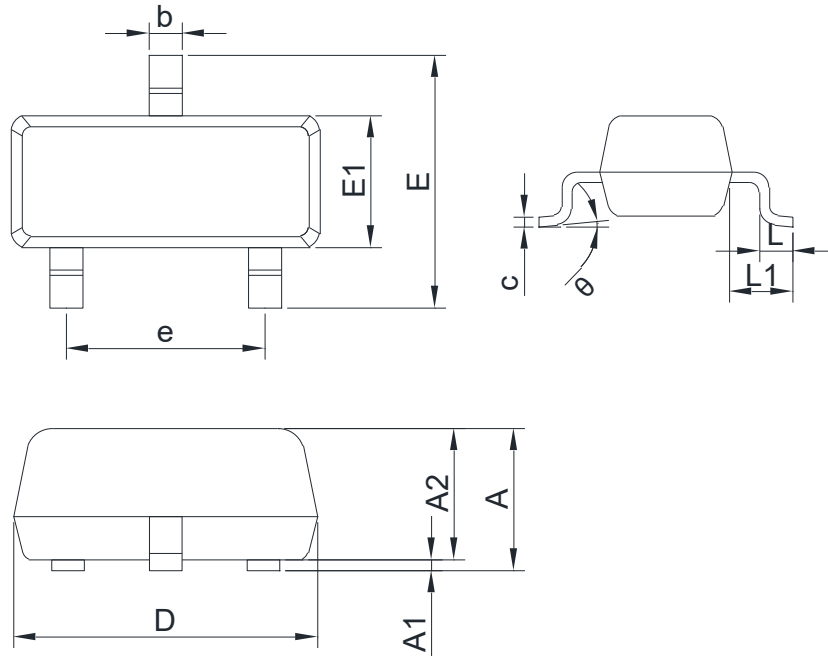
Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
<b>OFF CHARACTERISTICS</b>						
Drain-to-Source Breakdown Voltage	$BV_{DSS}$	$V_{GS}=0V, I_D=250\mu A$	20			V
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=20V, V_{GS}=0V$			1	$\mu A$
Gate-to-source Leakage Current	$I_{GSS}$	$V_{DS}=0V, V_{GS}=\pm 12V$			$\pm 100$	nA
<b>ON CHARACTERISTICS</b>						
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{GS}=V_{DS}, I_D=250\mu A$	0.5	0.75	1.0	V
Drain-to-source On-resistance	$R_{DS(on)}$	$V_{GS}=4.5V, I_D=4A$		25	32	m $\Omega$
		$V_{GS}=2.5V, I_D=3A$		29	38	
<b>CHARGES, CAPACITANCES AND GATE RESISTANCE</b>						
Input Capacitance	$C_{ISS}$	$V_{GS}=0V, f=1MHz, V_{DS}=10V$		470		pF
Output Capacitance	$C_{OSS}$			55		
Reverse Transfer Capacitance	$C_{RSS}$			50		
Total Gate Charge	$Q_{G(TOT)}$	$V_{GS}=4.5V, V_{DS}=10V, I_D=2A$		6		nC
Gate-to-Source Charge	$Q_{GS}$			1		
Gate-to-Drain Charge	$Q_{GD}$			1.5		
<b>SWITCHING CHARACTERISTICS</b>						
Turn-On Delay Time	$t_{d(ON)}$	$V_{GS}=4.5V, V_{DS}=10V, I_D=2A, R_G=3\Omega$		4		ns
Rise Time	$t_r$			13		
Turn-Off Delay Time	$t_{d(OFF)}$			65		
Fall Time	$t_f$			33		
<b>BODY DIODE CHARACTERISTICS</b>						
Forward Voltage	$V_{SD}$	$V_{GS}=0V, I_S=4A$			1.5	V

## 7. Typical Characteristic



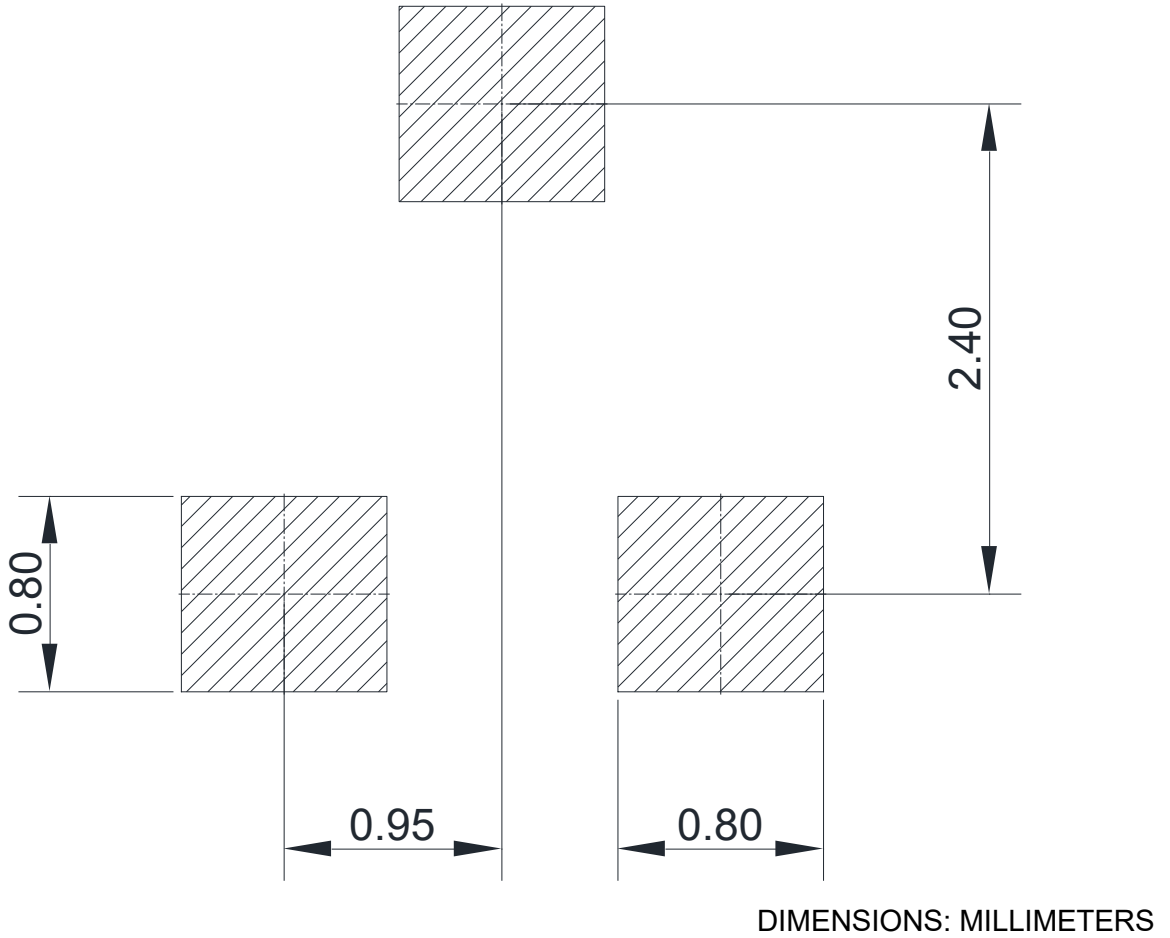
8. Dimension (SOT-23)

POD(Z)



COMMON DIMENSIONS CUNITS MEASURE=MILLIMETER					
SYMBOL	MIN	MAX	SYMBOL	MIN	MAX
A	0.90	1.20	E	2.25	2.55
A1	0.00	0.10	E1	1.20	1.40
A2	0.90	1.10	e	1.80	2.00
b	0.30	0.50	L	0.30	0.50
c	0.07	0.18	L1	0.475	0.625
D	2.80	3.04	theta	0°	8°

9. Recommended Soldering Footprint



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